

Technical Data
Data Sheet N1523, Rev. -

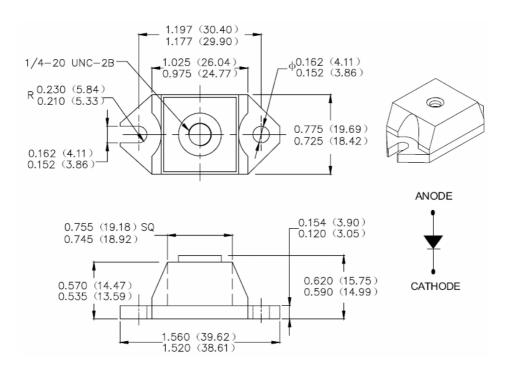
Green Products

120NQ600-1 Ultrafast Recovery Modules

Features:

- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm



PRM1-1(HALF PAK Module)

MARKING, MOLDING RESIN

Marking for 120NQ600-1, 1st row SS YYWWL, 2nd row 120NQ600-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	600	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =100℃, rectangular wave form	120	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	1200	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 120A, Pulse, T _J = 25 °C	1.70	V
Reverse Current (per leg) *	I_{R1}	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	30	μΑ
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$	1000	pF
(per leg)	O _T	$f_{SIG} = 1MHz$	1000	рі
Reverse Recovery Time(Note 1)	t _{rr}	I_F =0.5A, I_R =1A,and I_{RR} =0.25A	100	ns
Voltage Rate of Change	dv/dt	-	10,000	V/μs

 $^{^{\}star}$ Pulse Width < 300 $\mu s,$ Duty Cycle <2% Note1.Preliminary.

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specifi	Units			
Junction Temperature	T_J	-	-55 to +150		°C		
Storage Temperature	T_{stg}	-	-55 to +150		°C		
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.50		°C/W		
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.012		°C/W		
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal	23(min) 29(max) 35(min)	Kg-cm		
Approximate Weight	wt	-	Torque 46(max) 25.6		g		
Case Style	PRM1-1						

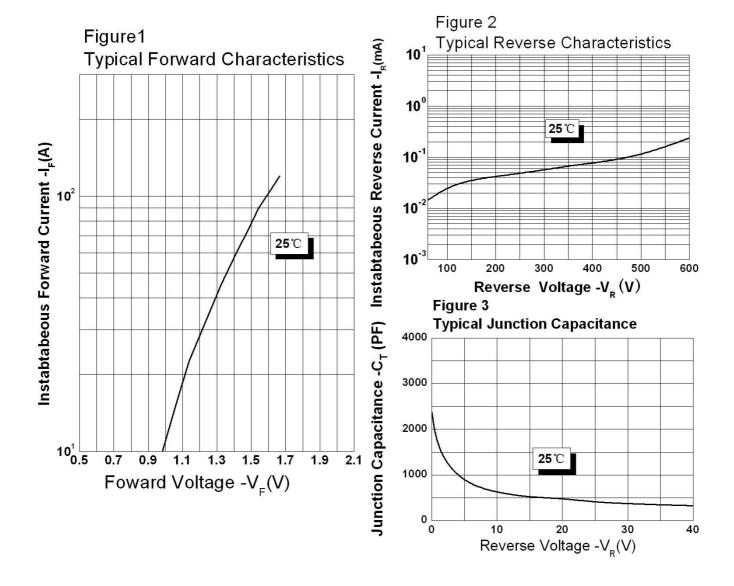
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